# **Power MOSFET**

# 40 V, 51 A, Single N-Channel, DPAK/IPAK

#### **Features**

- Low R<sub>DS(on)</sub>
- High Current Capability
- Avalanche Energy Specified
- These are Pb-Free Devices

## **Applications**

- LED Backlight Driver
- CCFL Backlight
- DC Motor Control
- Power Supply Secondary Side Synchronous Rectification

## **MAXIMUM RATINGS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V <sub>DSS</sub>	40	V
Gate-to-Source Voltag	e – Contir	nuous	V <sub>GS</sub>	±20	V
Gate-to-Source Voltage - Non-Repetitive (t <sub>p</sub> < 10 μS)			$V_{GS}$	±30	V
Continuous Drain		T <sub>C</sub> = 25°C	I <sub>D</sub>	51	Α
Current (R <sub>θJC</sub> ) (Note 1)	Steady State	T <sub>C</sub> = 100°C		36	
Power Dissipation (R <sub>θJC</sub> ) (Note 1)	State	T <sub>C</sub> = 25°C	P <sub>D</sub>	47	W
Pulsed Drain Current	t <sub>p</sub> =	= 10 μs	I <sub>DM</sub>	85	Α
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C
Source Current (Body Diode)			I <sub>S</sub>	30	Α
Single Pulse Drain-to-Source Avalanche Energy ( $V_{DD}$ = 50 V, $V_{GS}$ = 10 V, $R_{G}$ = 25 $\Omega$ , $I_{L(pk)}$ = 40 A, L = 0.1 mH, $V_{DS}$ = 40 V)			E <sub>AS</sub>	80	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			T <sub>L</sub>	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case (Drain)	$R_{\theta JC}$	3.2	°C/W
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	107	

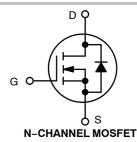
<sup>1.</sup> Surface–mounted on FR4 board using the minimum recommended pad size.



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V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> MAX	I <sub>D</sub> MAX	
40 V	16 m $\Omega$ @ 5.0 V	51 A	
40 V	9.5 mΩ @ 10 V	DIA	



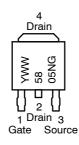


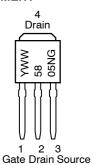




CASE 369D IPAK (Straight Lead DPAK)

# MARKING DIAGRAMS & PIN ASSIGNMENT





Y = Year

WW = Work Week

5805N = Device Code

G = Pb-Free Package

#### **ORDERING INFORMATION**

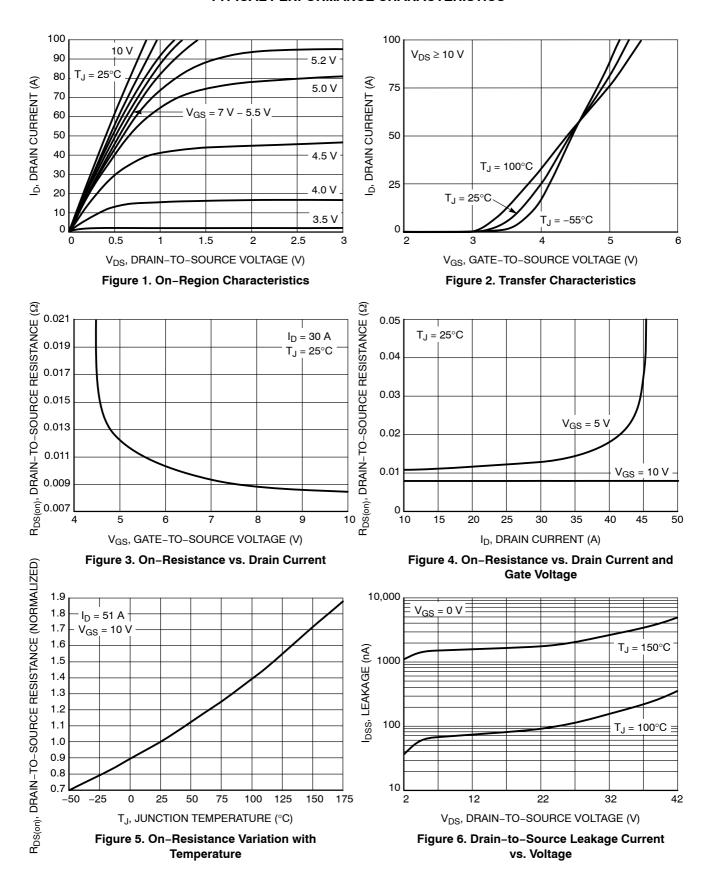
See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	•					•	•
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>				40.8		mV/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V.	T <sub>J</sub> = 25°C			1.0	μΑ
		$V_{GS} = 0 V$ , $V_{DS} = 40 V$	T <sub>J</sub> = 150°C			100	1
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{G}$	<sub>S</sub> = ±20 V			±100	nA
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_{D}$	= 250 μΑ	1.5		3.5	V
Negative Threshold Temperature Coefficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				7.04		mV/°C
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I	<sub>D</sub> = 15 A		7.6	9.5	mΩ
	•	V <sub>GS</sub> = 5.0 V, I	<sub>D</sub> = 10 A		10.9	16	1
Forward Transconductance	gFS	V <sub>DS</sub> = 15 V, I	<sub>O</sub> = 15 A		8.54		S
CHARGES, CAPACITANCES AND GA	TE RESISTANCE	S			•		
Input Capacitance	C <sub>iss</sub>				1725		pF
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 \text{ V, f} = 1.0 \text{ MHz,}$ $V_{DS} = 25 \text{ V}$			220		1
Reverse Transfer Capacitance	C <sub>rss</sub>				160		1
Total Gate Charge	Q <sub>G(TOT)</sub>				33	80	nC
Threshold Gate Charge	Q <sub>G(TH)</sub>	$V_{GS} = 10 \text{ V}, V_{DS} = 32 \text{ V},$ $I_{D} = 30 \text{ A}$			2.0		1
Gate-to-Source Charge	Q <sub>GS</sub>				7.2		1
Gate-to-Drain Charge	$Q_{GD}$				9.8		1
SWITCHING CHARACTERISTICS (No	te 3)				•		
Turn-On Delay Time	t <sub>d(on)</sub>				10.2		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V, V <sub>E</sub>	nn = 32 V.		17.9		1
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D = 30 \text{ A}, R_G$	$= 2.5 \Omega$		22.9		1
Fall Time	t <sub>f</sub>				4.5		1
DRAIN-SOURCE DIODE CHARACTEI	RISTICS				•	•	•
Forward Diode Voltage	$V_{SD}$	V <sub>GS</sub> = 0 V,	T <sub>J</sub> = 25°C		0.83	1.2	V
		I <sub>S</sub> = 10 A	T <sub>J</sub> = 150°C		0.65		7
Reverse Recovery Time	t <sub>RR</sub>	V <sub>GS</sub> = 0 V, dls/dt = 100 A/μs, I <sub>S</sub> = 30 A			24.8		ns
Charge Time	ta				14.6		1
Discharge Time	tb				10.2		1
Reverse Recovery Charge	Q <sub>RR</sub>				15.5		nC

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.

#### TYPICAL PERFORMANCE CHARACTERISTICS



## TYPICAL PERFORMANCE CHARACTERISTICS

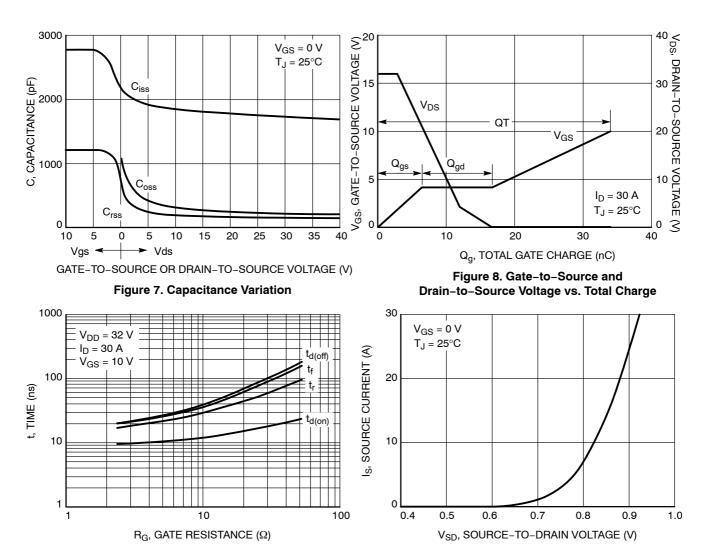


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

Figure 10. Diode Forward Voltage vs. Current

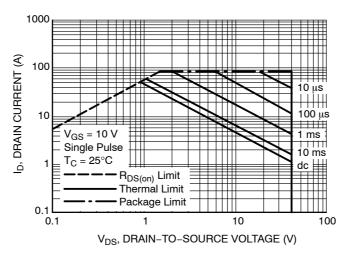


Figure 11. Maximum Rated Forward Biased Safe Operating Area

## TYPICAL PERFORMANCE CHARACTERISTICS

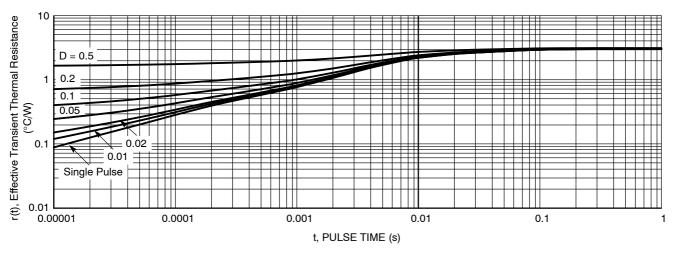


Figure 12. Thermal Response

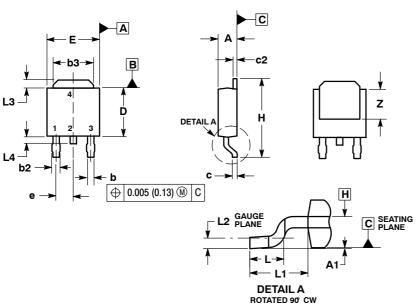
## **ORDERING INFORMATION**

Order Number	Package	Shipping <sup>†</sup>	
NTD5805NG	IPAK (Straight Lead DPAK) (Pb-Free)	75 Units / Rail	
NTD5805NT4G	DPAK (Pb-Free)	2500 / Tape & Reel	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### PACKAGE DIMENSIONS

## **DPAK** CASE 369C-01 ISSUE D



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: INCHES.

  3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.

  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.

  5. DIMENSIONS D AND E ARE DETERMINED AT THE
- NOT EXCEED USUG INCITES PER SIDE.

  5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.

  6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

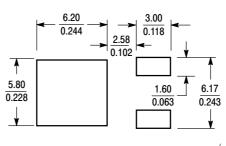
	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.086	0.094	2.18	2.38	
<b>A</b> 1	0.000	0.005	0.00	0.13	
b	0.025	0.035	0.63	0.89	
b2	0.030	0.045	0.76	1.14	
b3	0.180	0.215	4.57	5.46	
С	0.018	0.024	0.46	0.61	
c2	0.018	0.024	0.46	0.61	
D	0.235	0.245	5.97	6.22	
Е	0.250	0.265	6.35	6.73	
е	0.090	BSC	2.29 BSC		
Н	0.370	0.410	9.40	10.41	
L	0.055	0.070	1.40	1.78	
L1	0.108 REF		2.74 REF		
L2	0.020 BSC		0.51 BSC		
L3	0.035	0.050	0.89	1.27	
L4		0.040		1.01	
Z	0.155		3.93		

STYLE 2: PIN 1. GATE

2. DRAIN 3. SOURCE

DRAIN

### **SOLDERING FOOTPRINT\***



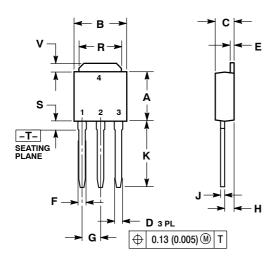
(mm inches SCALE 3:1

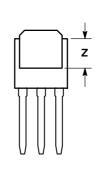
<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

### **IPAK (STRAIGHT LEAD DPAK)**

CASE 369D-01 ISSUE B





#### NOTES:

- DIMENSIONING AND TOLERANCING PER
   ANSLY 14 FM 1982
- ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090	BSC	2.29 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
٧	0.035	0.050	0.89	1.27
Z	0.155		3.93	

STYLE 2:

PIN 1. GATE

- DRAIN
- 3. SOURCE
- 4. DRAIN

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